



BC847BFAQ

45V NPN SMALL SIGNAL TRANSISTOR IN DFN0806

Description

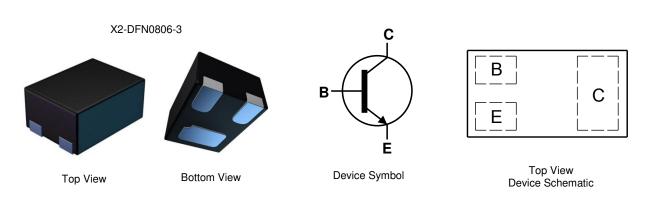
This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Features

- BV_{CEO} > 45V
- I_C = 100mA High Collector Current
- P_D = 435mW Power Dissipation
- 0.48mm² Package Footprint, 16 Times Smaller than SOT23
- 0.4mm Height Package Minimizing Off-Board Profile
- Complementary PNP Type BC857BFA
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: X2-DFN0806-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu, Solderable per MIL-STD-202, Method 208 @
- Weight: 0.0008 grams (Approximate)



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BC847BFAQ-7B	Automotive	1F	7	8mm	10,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:

X2-DFN0806-3



1F = Product Type Marking Code

Top View Bar Denotes Base and Emitter Side



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	45	V
Emitter-Base Voltage	V _{EBO}	6.0	V
Continuous Collector Current	IC	100	mA
Peak Pulse Collector Current	I _{CM}	200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	435	mW
Thermal Resistance, Junction to Ambient (Note 6)	R _{θJA}	287	°C/W
Thermal Resistance, Junction to Lead (Note 8)	R _{θJL}	150	°C/W
Operating and Storage and Temperature Range	TJ, TSTG	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class	
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	ЗA	
Electrostatic Discharge – Machine Model	ESD MM	200	V	В	

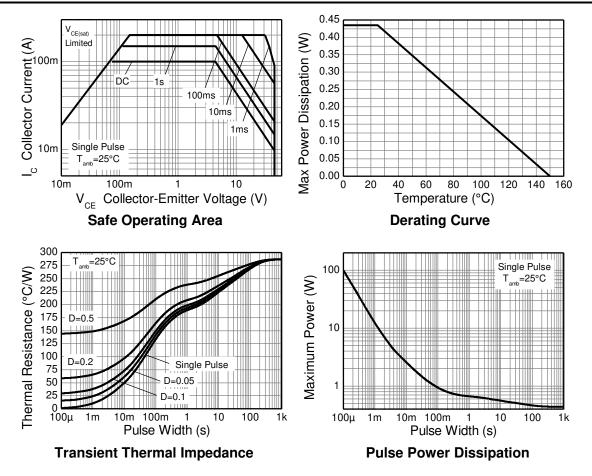
Notes: 6. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured

under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink. 7. Thermal resistance from junction to solder-point (on the exposed collector pad).

8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





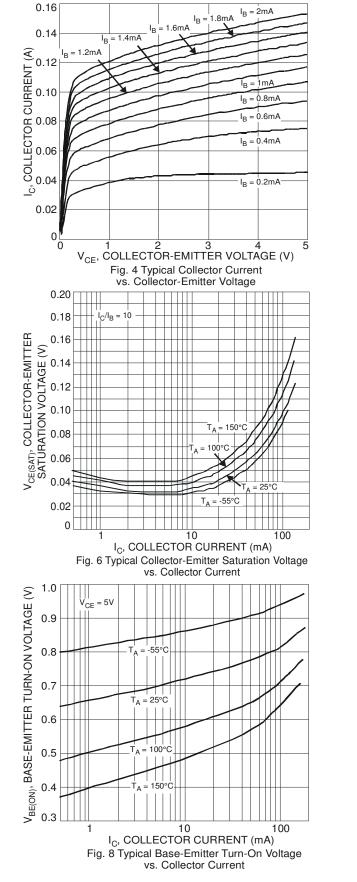
Electrical Characteristics	$(@T_A = +25^{\circ}C, unless otherwise specified.)$
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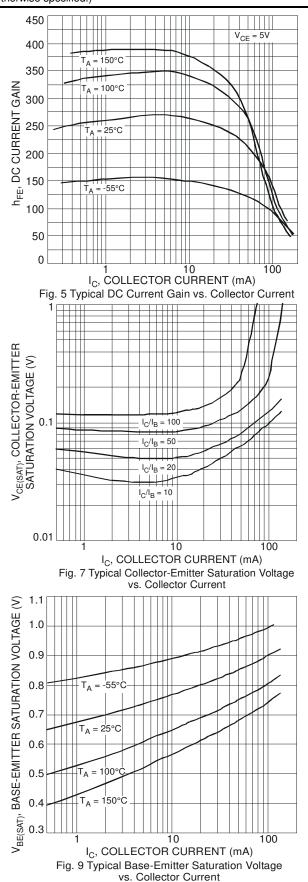
Characteristic	Symbol	Min	Typical	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	50	150	_	V	$I_{\rm C} = 50 \mu A, I_{\rm B} = 0$
Collector-Emitter Breakdown Voltage	BV _{CES}	50	150	—		$I_{\rm C} = 50 \mu A, I_{\rm B} = 0$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	45	65	_	V	$I_{C} = 1mA, I_{B} = 0$
Collector-Base Breakdown Voltage	BV _{EBO}	6.0	8.35	—	V	$I_{E} = 50 \mu A, I_{C} = 0$
Collector-Base Cutoff Current	I _{CBO}	_		15	nA	$V_{CB} = 40V$
Collector-Emitter Cutoff Current	ICES		_	15	nA	$V_{CE} = 40V$
ON CHARACTERISTICS (Note 9)						
DC Current Gain	h	_	220	_	_	$I_{C} = 10 \mu A, V_{CE} = 5.0 V$
DC Current Gain	h _{FE}	200	260	470		$I_{C} = 2.0 \text{mA}, V_{CE} = 5.0 \text{V}$
Collector-Emitter Saturation Voltage	V	т) —	50	125	mV	$I_{C} = 10mA, I_{B} = 0.5mA$
	V _{CE(SAT)}		122	122 300		$I_C = 100 mA$, $I_B = 5.0 mA$
Base-Emitter Saturation Voltage	Variation		760	1,000 mV	m٧	$I_{C} = 10 mA$, $I_{B} = 0.5 mA$
	$V_{BE(SAT)}$		880	1,100	IIIV	$I_{C} = 100 \text{mA}, I_{B} = 5.0 \text{mA}$
Base-Emitter Voltage	Varian	580	650 750	mV	$I_{C} = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
	V _{BE(ON)}	_	725	800	IIIV	$I_{C} = 10 mA, V_{CE} = 5V$
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	Сово		1.5	—	pF	$V_{CB} = 10.0V, f = 1.0MHz, I_E = 0$
Current Gain-Bandwidth Product	fT	100	170		MHz	$V_{CE} = 5V, I_{C} = 10mA,$
	11	100	170			f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.





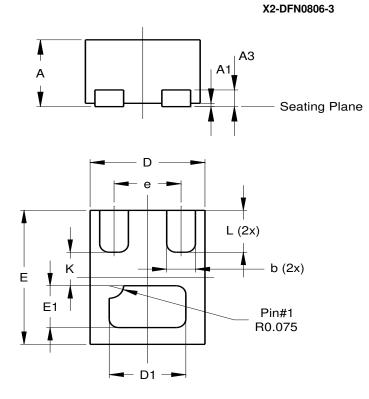






Package Outline Dimensions

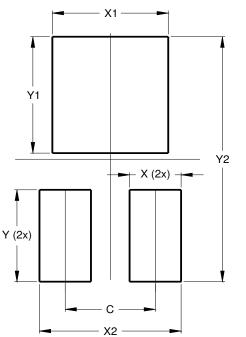
Please see http://www.diodes.com/package-outlines.html for the latest version.



X2-DFN0806-3				
Dim	Min	Max	Тур	
Α	0.375	0.40	0.39	
A1	0	0.05	0.02	
A3	_	-	0.10	
b	0.10	0.20	0.15	
D	0.55	0.65	0.60	
D1	0.35	0.45	0.40	
Е	0.75	0.85	0.80	
E1	0.20	0.30	0.25	
е	-	-	0.35	
К	-	-	0.20	
L	0.20	0.30	0.25	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.350
Х	0.200
X1	0.450
X2	0.550
Y	0.375
Y1	0.475
Y2	1.000



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